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Observation of double resistance anomalies and excessive resistance in mesoscopic superconducting $Au_{0.7}In_{0.3}$ rings with phase separation

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We have measured mesoscopic superconducting $Au_{0.7}In_{0.3}$ rings prepared by e-beam lithography and sequential deposition of Au and In at room temperature followed by a standard lift-off procedure. In samples showing no Little-Parks resistance oscillations, highly unusual double resistance anomalies, two resistance peaks found near the onset of superconductivity, were observed. Although resistance anomaly featuring a single resistance peak has been seen in various mesoscopic superconducting samples, double resistance anomalies have never been observed previously. The dynamical resistance measurements suggest that there are two critical currents in these samples. In addition, the two resistance peaks were found to be suppressed at different magnetic fields. We attribute the observed double resistance anomalies to an underlying phase separation in which In-rich grains of intermetallic compound of AuIn precipitate in a uniform In-dilute matrix of $Au_{0.9}In_{0.1}$. The intrinsic superconducting transition temperature of the In-rich grains is substantially higher than that of the In-dilute matrix. The suppression of the conventional Little-Parks resistance oscillation is explained in the same picture by taking into consideration a strong variation in the T_c of the In-rich grains. We also report the observation of an unusual magnetic-field-induced metallic state with its resistance higher than the normal-state resistance, referred to here as excessive resistance, and an h/2e resistance oscillation with the amplitude of oscillation depends extremely weakly on temperature.

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Recent structural and electrical transport studies of $Au_{0.7}In_{0.3}$ films revealed an interesting phase separation in which In-rich grains, most likely intermetallic compound of AuIn, precipitate in a uniform In-dilute matrix, most likely $Au_{0.9}In_{0.1}$, with the superconducting transition temperature of the In-rich grains substantially higher than that of the In-dilute matrix, forming an array of superconductor-normal metal-superconductor (SNS) Josephson junctions[1], with both the local gap and Josephson coupling between adjacent In-rich grains varying randomly. These films represent a novel system for studying the disorder effects on superconductivity in two dimension (2D). Conventional granular films, such as those prepared by quench deposition, on the other hand, are modeled as a random array of superconductor-insulator-superconductor (SIS) Josephson junctions. The phase of the superconducting order parameter, ϕ, and the number of Cooper pairs, N, are conjugate variables quantum-mechanically, and are subject to an uncertainty relation. Therefore, the confinement of Cooper pairs in SIS granular films due to charging energy leads to the phase fluctuation, and a 2D superconductor-to-insulator transition (SIT) if the phase fluctuation is sufficiently strong. Cooper pairs in $Au_{0.7}In_{0.3}$ films, however, are not subject to similar spatial confinement. Nevertheless, a quantum superconductor-normal metal phase transition (SNT) is still expected in such a random array of SNS Josephson junctions, as predicted theoretically recently [4,5].

Experimentally interesting physical phenomena have been found in planar and cylindrical films of $Au_{0.7}In_{0.3}$[2,3]. In particular, an h/4e, rather than h/2e, resistance oscillation, was found[3]. While the physical origin of this h/4e resistance oscillation is not fully understood, it may be associated with the presence of π-junctions between adjacent In-rich grains that possess a negative rather than positive Josephson coupling constant[3]. Such negative Josephson coupling could be derived from mesoscopic fluctuation or correlation effects[6,7]. The presence of these random distributed π-junctions leads to an h/4e resistance oscillation because of the ensemble average[7]. In single mesoscopic rings of $Au_{0.7}In_{0.3}$, the resistance oscillation is expected to be of the conventional h/2e period, but with an unconventional phase shift by π if the number of π-junctions in the ring is odd. No phase shift is expected for rings with even number of π-junctions.

In this paper, we report our experimental studies of mesoscopic superconducting $Au_{0.7}In_{0.3}$ rings prepared by e-beam lithography and sequential deposition of Au and In at room temperature followed by a standard lift-off procedure. Conventional h/2e resistance oscillation was observed, as expected. However, whether there is a phase shift by π in the h/2e oscillation is not determined because of technical issues (see below). On the other hand, in samples where the conventional Little-Parks (L-P) resistance oscillation was suppressed, double resistance anomalies and a magnetic-field-induced metallic state with excessive resistance were found. We attribute these observations to the separation of In-rich and In-dilute phases in these rings.

Conventional e-beam lithography was used to prepare the $Au_{0.7}In_{0.3}$ rings. The pattern of several rings were generated using double-layer PMMA/MMA resist on polished 1cm×1cm sapphire substrate. Sequential thermal evaporation of alternating 99.9999% pure Au and In lay-

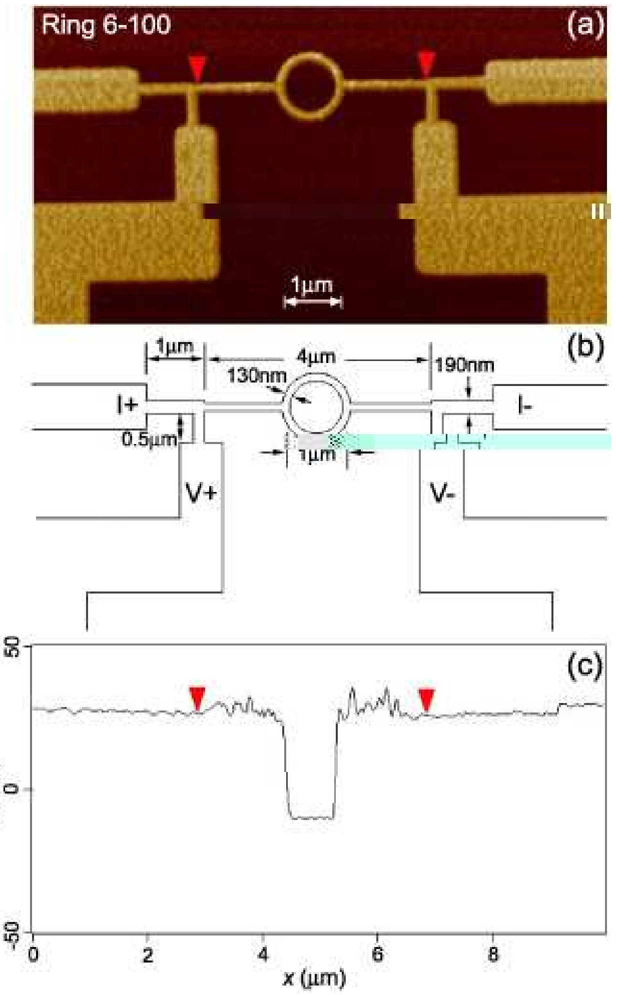

FIG. 1: a) Atomic force microscope (AFM) image of a 1-μm-diam $Au_{0.7}In_{0.3}$ ring (6-100, see Table I); b) Schematic corresponding to the AFM image in Fig. 1a; c) Height profile along the ring arms showing surface roughness.

ers, with the layer thickness determined by the appropriate atomic ratio of Au to In, was carried out at ambient temperature in a conventional evaporator with a vacuum of 1×10^{-6} torr or slightly better. The ring pattern was placed with respect to the Au and In sources so as to minimize the shadow effects during evaporation. Atomic force microscope (AFM) was used to image the resulted $Au_{0.7}In_{0.3}$ rings before and/or after the measurements. The electrical transport measurements were carried out in a dilution fridge which is equipped with a superconducting magnet and has a base temperature <20mK. All electrical leads entering the cryostat were filtered by RF filters with an attenuation of 10dB at 10MHz and 50dB at 300MHz. Resistance characteristics were measured with a d.c. current source and a nanovoltmeter. The magnetic field was applied perpendicular to the substrate, the plane of the rings.

Five rings were measured in this study. Two rings have a diameter of 0.75μm and the rest have a diameter of 1μm. The thickness of all rings is nominally 30 nm. An AFM image of a 1-μm-diam ring, Sample 6-100, is shown in Fig. 1a, with a schematic shown in Fig. 1b to detail the various dimensions of the sample. Rings with a 0.75-μm diameter have the same layout with a 4 μm voltage-probe separation. Two features of the samples should be noted. First, as seen in the schematic of the sample (Fig. 1b), the linewidth increases slightly at the nodes of the voltage leads going towards the large contact pads. Such variation of the linewidth, observed in all samples, was probably due to an overexposure while writing the large contact pads; Second, the surface roughness as seen by AFM increases at the narrow part of the sample (within the voltage leads, see Fig. 1c). However, the cause for the increased height variations is not clear. We found in a separate study that the lift-off process we used for $Au_{0.7}In_{0.3}$ rings could generate rough edges (due to resist residue that is not lifted). Therefore the surface roughness may not necessarily indicate that the $Au_{0.7}In_{0.3}$ rings themselves have a rough surface.

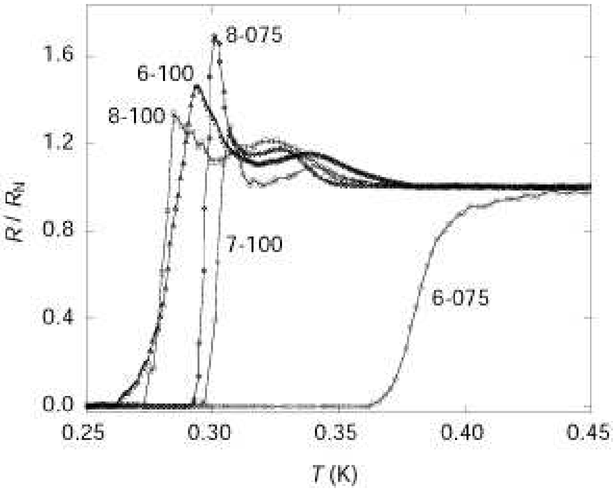

FIG. 2: Normalized resistances as function of temperature $R(T)$ for five $Au_{0.7}In_{0.3}$ rings. Rings are labeled as indicated. Parameters for these rings are shown in Table I.

In Fig. 2, normalized resistance as function of temperature under zero magnetic field is shown for all five rings. The structural and electrical parameters are listed in Table I. The typical values for the normal-state resistivity, ρ_N, are about 3 times larger than that for $Au_{0.7}In_{0.3}$ films with the same thickness[1], which is reasonable because of the extra surface scattering encountered in mesoscopic samples.

From Fig. 2 it is clear that there exist two types of behaviors among these rings. For Ring 6-075, a smooth resistive transition was seen. For other four rings, however, two resistance peaks were found near the onset of the superconducting transition. It is seen that the low-temperature resistance peak (LTRP) is relatively sharp, with a resistance about 30-70% higher than the normal-state resistance, R_N. The high-temperature resistance peak (HTRP) is broader and smaller in height (10-20%

TABLE I: Selected parameters for the rings. T_c is determined at the onset of the resistance drop for Ring 6-075, and for the rest of rings at the onset of the high-temperature resistance peak (HTRP). d is diameter. t is thickness.

Sample	d (μm)	t (nm)	$R_{\mathrm{N},\square}$ (Ω)	ρ_N ($\mu\Omega$ cm)	T_c (K)
6-075	0.75	30	13.5	40.6	0.450
6-100	1.00	30	13.5	40.4	0.380
7-100	1.00	30	12.5	37.4	0.370
8-075	0.75	30	11.3	33.8	0.359
8-100	1.00	30	12.4	37.2	0.355

higher than R_N) than LTRP.

The double resistance anomalies observed in these four rings are highly unusual. Single resistance anomaly, a resistance peak right at the onset of superconductivity, was previously observed in mesoscopic structures of Al and other materials [8,9,10,11,12,13,14]. Temperature dependence of the dynamical resistance as a function of bias current was also measured[8]. It seems reasonable that the double resistance anomalies observed in the current work and the previously observed single resistance anomaly share similar physical origin. Since the single resistance anomaly was found to occur at the onset of superconductivity, the occurrence of the double resistance peaks appears to indicate the existence of two superconducting phases with slightly different T_c's. Based on our previous work on planar $\mathrm{Au_{0.7}In_{0.3}}$ films[1], these two phases should be the In-rich grains, most likely intermetallic compound of AuIn, and the uniform In-dilute matrix, most likely $\mathrm{Au_{0.9}In_{0.1}}$. The superconducting transition temperatures of the In-rich grains are substantially higher than that of the In-dilute matrix. As a result, the sample can be viewed as an array of SNS Josephson junctions. In this picture, HTRP corresponds to that of the individual In-rich grains while LTRP is that of the junction array formed by the In-rich grains and the In-dilute matrix.

In Fig. 3b, we plot the differential resistance dV/dI as functions of the bias current I for Ring 6-100 at different temperatures of the resistive transition as marked by arrows in Fig. 3a. At $T = 0.26$K, sharp rises in dV/dI were seen (shown by the dash lines and by arrows at 0.26K), which appear to indicate the existence of two critical currents (I_c) in the sample. Essentially, the dynamical resistance is vanishing at low bias currents, and rises sharply at $\approx 0.05\mu$A, the lower critical current. The differential resistance minimum below the lower critical current was quickly suppressed by the increasing temperature, replaced by a central peak near zero bias current, indicating that the lower critical current vanishes. The peak at larger critical current was found to change only slightly with the increasing temperature, disappearing only when the entire sample turns normal.

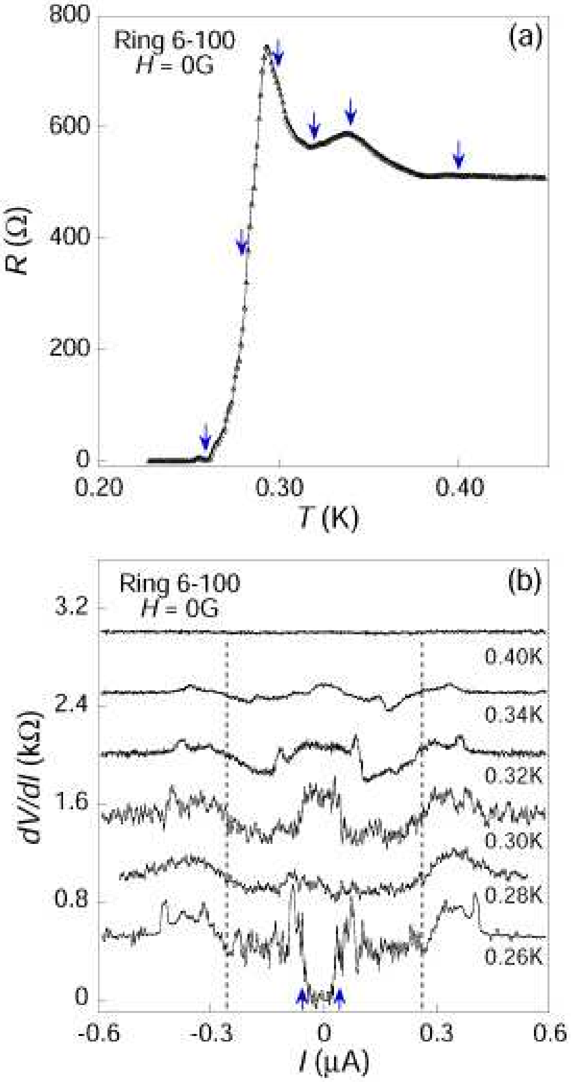

FIG. 3: a) Normalized $R(T)$ for Ring 6-100 in zero field. The temperatures at which dV/dI were taken (shown in b) are indicated by arrows; b) Differential resistance dV/dI (calculated from d.c. current biased $I-V$ curves using numerical derivatives) at various temperatures as indicated. Two critical currents are indicated by the dashed line and by the arrow. All curves except the one for $T = 0.26$K are shifted for clarity.

Results from the dynamical resistance measurements therefore supports the idea that the double resistance anomalies resulted from the phase separation. In fact, features found in the dynamical resistance in low currents (below 0.2μA) and their temperature dependence, especially the sharp rises above lower I_c and the emergence of a central peak near zero bias current, are consistent with those observed in mesoscopic Al wires with single resistance anomaly[8], suggesting that the smaller characteristic current is the critical current of the overall sample, the SNS junction array. The larger critical current would then correspond to that of the individual In-rich grains, which should drop slowly with increasing temperature.

The measurements on the magnetic field dependence of the double resistance anomalies, shown in Fig. 4, pro-

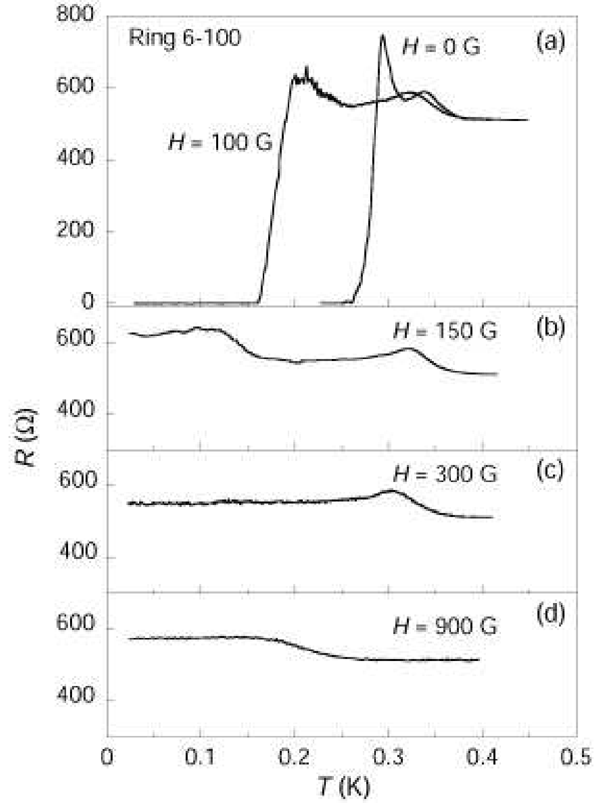

FIG. 4: $R(T)$ at several magnetic fields as indicated for Ring 6-100. The fields were applied perpendicular to the plane of the ring. A resistance plateau higher than R_{N} is shown down to the lowest temperature available (< 20mK) for $H = 300$ and 900G.

vided further support to the above picture. It is seen that LTRP is affected significantly at a field as low as 100G, becoming barely visible at 300G, which appears to be a critical field (H_c). On the other hand, in a field as high as 900G, even though HTRP is broadened and shifted to lower temperatures, it is clearly visible. In fact, even at field up to 1300G, HTRP could still be identified close to the lowest temperature, 20mK. It is therefore evident that the HTRP is associated with In-rich grains with a critical field of 1300G while LTRP belongs to the SNS junction array with a critical field of 300G.

The differential resistance curves taken at 300G (Fig. 5a) indeed show that, at 0.1K, the minimum near the zero bias current is replaced by a peak, indicating that the critical current of the SNS junction array is essentially zero at 300G. This is consistent with results of Fig. 4. This in turn supports the assessment that LTRP is associated with the SNS junction array. The sharp rise in dV/dI at high bias current, on the other hand, is clearly visible at $H = 900$G (Fig. 5b), suggesting that HTRP is associated with the In-rich grains.

An interesting feature emerging from Fig. 4 is that, in the intermediate field range, the broadened HTRP is seen to extended to the lowest temperature we measured.

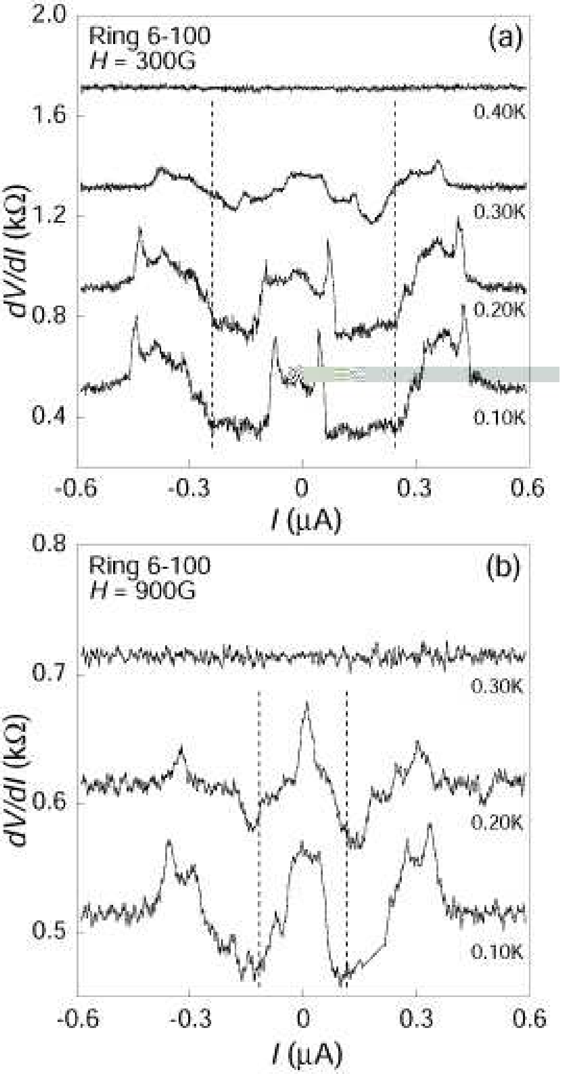

FIG. 5: a) Differential resistance dV/dI at various temperatures, as indicated, for Ring 6-100 at $H = 300G$; b) dV/dI at $H = 900$G. dV/dI curves are based on numerical derivatives of d.c. current biased $I - V$ measurements. All curves except the one at $T = 0.10$K are shifted for clarity in both panels.

At $H = 900$G, in particular, the resistance became independent of temperature down to 20mK, with a resistance value larger than that of the normal state R_{N}. The existence of this low-temperature resistance plateau, referred to here as excessive resistance, appears to suggest the existence of a metallic state in which the In-rich grains are superconducting, but not Josephson coupled. This metallic state cannot be due to heating as the onset of the metallic behavior (> 0.2K) is too high for electrons to be at temperatures higher than the lattice. The observation of a metallic state with its resistance larger than the normal state resistance and its onset temperature outside the low temperature region in which the heating is an issue, is itself a strong evidence that this metallic state is intrinsic. The physics of such a novel metallic state is yet

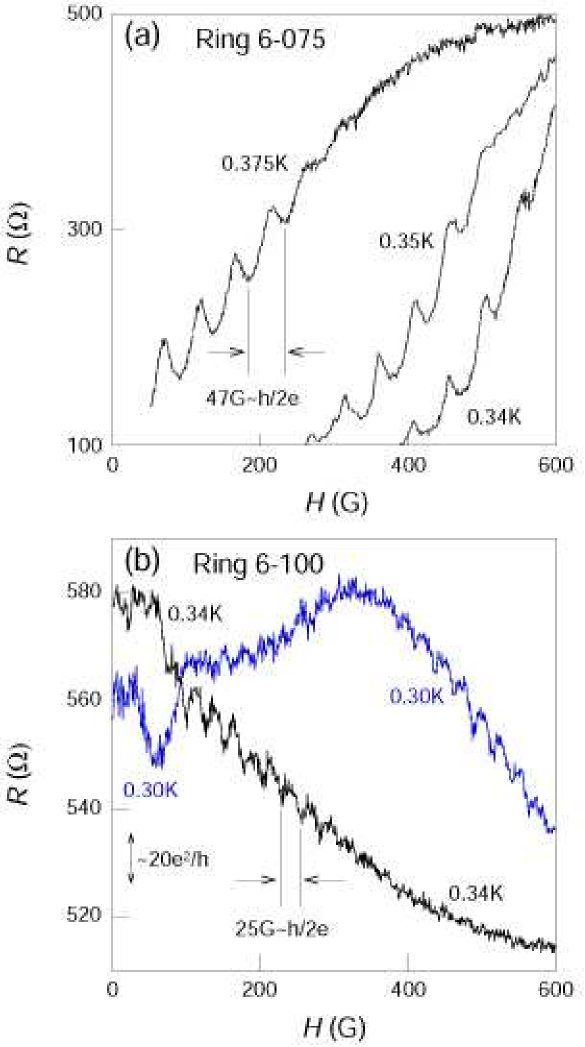

FIG. 6: a) Little-Parks resistance oscillation of Ring 6-075 at various temperatures as indicated. The period of the oscillation corresponds to h/2e; b) Magnetoresistance oscillations of Ring 6-100 at various temperatures as indicated. The resistance oscillation of a period of h/2e is due to coherent back scattering of single electrons. The resistance variation corresponding to $20e^2/h$ is shown.

to be explored.

For Ring 6-075 with a smooth $R(T)$ showing no double resistance anomalies, its onset T_c is around 0.45K, close to that observed in thinnest planar films (thickness $\leq$ 15nm) of $\mathrm{Au}_{0.7}\mathrm{In}_{0.3}$[1]. In those thinnest films, the interdiffusion of Au and In is suppressed by the close proximity to the substrate, resulting in films that are uniform rather than phase separated. Ring 6-075 may be of similarly uniform structure. This assessment is consistent with the observation of Little-Parks (L-P) resistance oscillation in this sample as shown in Fig. 6a, with a conventional period of h/2e. The observation of L-P resistance oscillation requires that the local T_c to be reasonably close across the sample to ensure a rigid shift of the $R(T)$ curves with the applied magnetic flux.

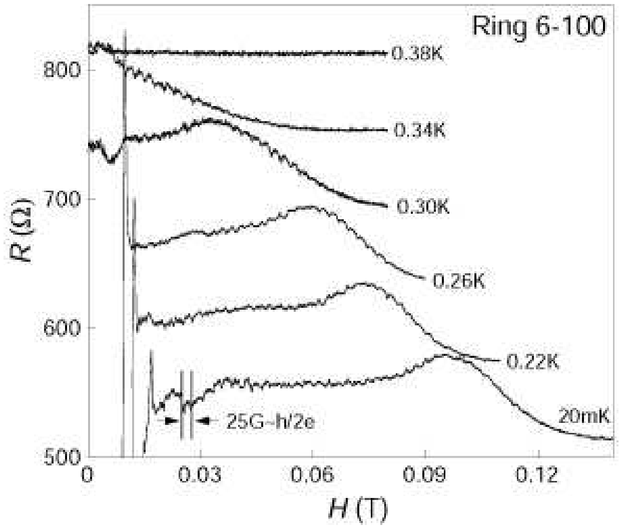

FIG. 7: Resistance as a function of applied magnetic field $R(H)$ at several temperatures, as indicated. The period of the resistance oscillations is h/2e. Essentially no change of the oscillation amplitude is seen from 0.34K down to 20mK. The negative magnetoresistance in the intermediate fields is related to the suppression of the resistance anomalies by the field. Curves are shifted for clarity except the one at 20mK.

We would like to mention that whether there was a phase shift by π in the h/2e oscillation in Ring 6-075, the question that motivated this work originally, could not be determined. We found it difficult to determine the flux sufficiently precisely because of the possibility of trapping flux in the superconducting magnet.

For other four rings showing double resistance anomalies, the T_{c} of the In-rich grains will depend sensitively on the atomic composition, the size, and the level of intragrain disorder. Since the L-P resistance oscillation relies on the rigid shift of $R(T)$ curve with the applied magnetic flux, a strongly varying local T_c will suppress the L-P resistance oscillation. Indeed, experimentally, the L-P resistance oscillation was not observed in the phase separated rings. Only a weak h/2e resistance oscillation was found from near the transition temperatures down to the base temperature 20 mK (Fig. 6b). The amplitude of this oscillation is much smaller than the L-P oscillation in Ring 6-075 (Fig. 6a). As a result, this oscillation should be the Sharvin-Sharvin (S-S) oscillation[15], predicted theoretically by Altshuler and Aronov[16]. This oscillation originates from the coherent backscattering of normal electrons in disordered systems, a weak localization phenomenon. In terms of conductance, $\Delta G \approx 11e^2/h$, where an effective normal-state resistance of the ring itself, 105.8Ω (estimated from the sample geometry), rather than the total resistance of the sample, 510Ω, is used. Clearly, the S-S oscillation is enhanced due to the existence of superconducting In-rich grains in the sample[2,17,18]. This also explains why S-S resistance oscillation was observed only below the onset of superconductivity ($T = 0.38$K). Above $T = 0.38$K, the dephasing length, L_φ, is smaller than the circumference of the ring, $L = \pi d$. As the In-rich grains becomes superconducting, dephasing occurs only in the In-dilute matrix, making the effective circumference smaller than L_φ. The associated negative magnetoresistance background shown in Fig. 6b is related primarily to the suppression of the resistance anomalies by magnetic field.

While h/2e resistance oscillation observed in the phase separated rings is clearly S-S resistance oscillation, the temperature dependence of the amplitude of the oscillation is puzzling. Over a wide range of temperature, from 0.34K down to 20mK (Fig. 7), the amplitude of the resistance oscillation is hardly changed. As the amplitude of S-S oscillation depends on the dephasing length, and the dephasing length increases with decreasing temperature, the resistance oscillations should increase in amplitude as the temperature is lowered. More experimental and theoretical work is needed to clarify this issue.

In closing, we would like to comment on the possible physical origin of the double resistance anomalies. Clearly the double resistance anomalies must be due to similar physical process as the single resistance anomaly observed previously in uniform mesoscopic superconducting samples. Unfortunately, the physical origin of the single resistance anomaly is still subject to an intensive debate [8,9,10,11,12,13,14] and is not settled. One school of thoughts has argued that charge imbalance near the superconductor-normal metal (SN) interface contributes to the resistance anomaly[9,10,12,13] while another school has pursued an alternative model based on the potential step at the SN interface and the effects of the interface shape[11,14]. Given this, it is perhaps reasonable to delay this question regarding the precise physical origin of the double resistance anomalies and the related excessive resistance to future inquiries.

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